

# Standard Rectifier Module

$$V_{RRM} = 2 \times 1600 \text{ V}$$

$$I_{FAV} = 110 \text{ A}$$

$$V_F = 1.14 \text{ V}$$

Phase leg

Part number

**MDMA110P1600TG**



Backside: isolated

 E72873



## Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

## Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

## Disclaimer Notice

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| Rectifier  |                                              |                                            |                                           | Ratings                        |      |      |                   |
|------------|----------------------------------------------|--------------------------------------------|-------------------------------------------|--------------------------------|------|------|-------------------|
| Symbol     | Definition                                   | Conditions                                 |                                           | min.                           | typ. | max. | Unit              |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$              |                                           |                                |      | 1700 | V                 |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$              |                                           |                                |      | 1600 | V                 |
| $I_R$      | reverse current                              | $V_R = 1600\text{ V}$                      | $T_{VJ} = 25^{\circ}\text{C}$             |                                |      | 100  | $\mu\text{A}$     |
|            |                                              | $V_R = 1600\text{ V}$                      | $T_{VJ} = 150^{\circ}\text{C}$            |                                |      | 2    | mA                |
| $V_F$      | forward voltage drop                         | $I_F = 110\text{ A}$                       | $T_{VJ} = 25^{\circ}\text{C}$             |                                |      | 1.21 | V                 |
|            |                                              | $I_F = 220\text{ A}$                       |                                           |                                |      | 1.44 | V                 |
|            |                                              | $I_F = 110\text{ A}$                       | $T_{VJ} = 125^{\circ}\text{C}$            |                                |      | 1.14 | V                 |
|            |                                              | $I_F = 220\text{ A}$                       |                                           |                                |      | 1.44 | V                 |
| $I_{FAV}$  | average forward current                      | $T_C = 100^{\circ}\text{C}$<br>rectangular | $T_{VJ} = 150^{\circ}\text{C}$<br>d = 0.5 |                                |      | 110  | A                 |
| $V_{F0}$   | threshold voltage                            | } for power loss calculation only          |                                           | $T_{VJ} = 150^{\circ}\text{C}$ |      | 0.82 | V                 |
| $r_F$      | slope resistance                             |                                            |                                           |                                |      | 2.8  | m $\Omega$        |
| $R_{thJC}$ | thermal resistance junction to case          |                                            |                                           |                                |      | 0.3  | K/W               |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                            |                                           |                                | 0.2  |      | K/W               |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                 |                                           |                                |      | 415  | W                 |
| $I_{FSM}$  | max. forward surge current                   | t = 10 ms; (50 Hz), sine                   | $T_{VJ} = 45^{\circ}\text{C}$             |                                |      | 2.00 | kA                |
|            |                                              | t = 8,3 ms; (60 Hz), sine                  | $V_R = 0\text{ V}$                        |                                |      | 2.16 | kA                |
|            |                                              | t = 10 ms; (50 Hz), sine                   | $T_{VJ} = 150^{\circ}\text{C}$            |                                |      | 1.70 | kA                |
|            |                                              | t = 8,3 ms; (60 Hz), sine                  | $V_R = 0\text{ V}$                        |                                |      | 1.84 | kA                |
| $I^2t$     | value for fusing                             | t = 10 ms; (50 Hz), sine                   | $T_{VJ} = 45^{\circ}\text{C}$             |                                |      | 20.0 | kA <sup>2</sup> s |
|            |                                              | t = 8,3 ms; (60 Hz), sine                  | $V_R = 0\text{ V}$                        |                                |      | 19.4 | kA <sup>2</sup> s |
|            |                                              | t = 10 ms; (50 Hz), sine                   | $T_{VJ} = 150^{\circ}\text{C}$            |                                |      | 14.5 | kA <sup>2</sup> s |
|            |                                              | t = 8,3 ms; (60 Hz), sine                  | $V_R = 0\text{ V}$                        |                                |      | 14.0 | kA <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$     |                                           |                                | 73   |      | pF                |

| Package TO-240AA |                                                              |                      |                                     | Ratings |      |      |      |
|------------------|--------------------------------------------------------------|----------------------|-------------------------------------|---------|------|------|------|
| Symbol           | Definition                                                   | Conditions           |                                     | min.    | typ. | max. | Unit |
| $I_{RMS}$        | RMS current                                                  | per terminal         |                                     |         |      | 200  | A    |
| $T_{VJ}$         | virtual junction temperature                                 |                      |                                     | -40     |      | 150  | °C   |
| $T_{op}$         | operation temperature                                        |                      |                                     | -40     |      | 125  | °C   |
| $T_{stg}$        | storage temperature                                          |                      |                                     | -40     |      | 125  | °C   |
| <b>Weight</b>    |                                                              |                      |                                     |         | 76   |      | g    |
| $M_D$            | mounting torque                                              |                      |                                     | 2.5     |      | 4    | Nm   |
| $M_T$            | terminal torque                                              |                      |                                     | 2.5     |      | 4    | Nm   |
| $d_{Spp/Apb}$    | creepage distance on surface   striking distance through air | terminal to terminal | 13.0                                | 9.7     |      |      | mm   |
| $d_{Spp/Apb}$    |                                                              | terminal to backside | 16.0                                | 16.0    |      |      | mm   |
| $V_{ISOL}$       | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 4800    |      |      | V    |
|                  |                                                              | t = 1 minute         |                                     | 4000    |      |      | V    |



### Part description

M = Module  
 D = Diode  
 M = Standard Rectifier  
 A = (up to 1800V)  
 110 = Current Rating [A]  
 P = Phase leg  
 1600 = Reverse Voltage [V]  
 TG = TO-240AA

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MDMA110P1600TG  | MDMA110P1600TG     | Box           | 36       | 514311   |

### Equivalent Circuits for Simulation

\* on die level

$T_{VJ} = 150^{\circ}\text{C}$



Rectifier

$V_{0\max}$  threshold voltage 0.82

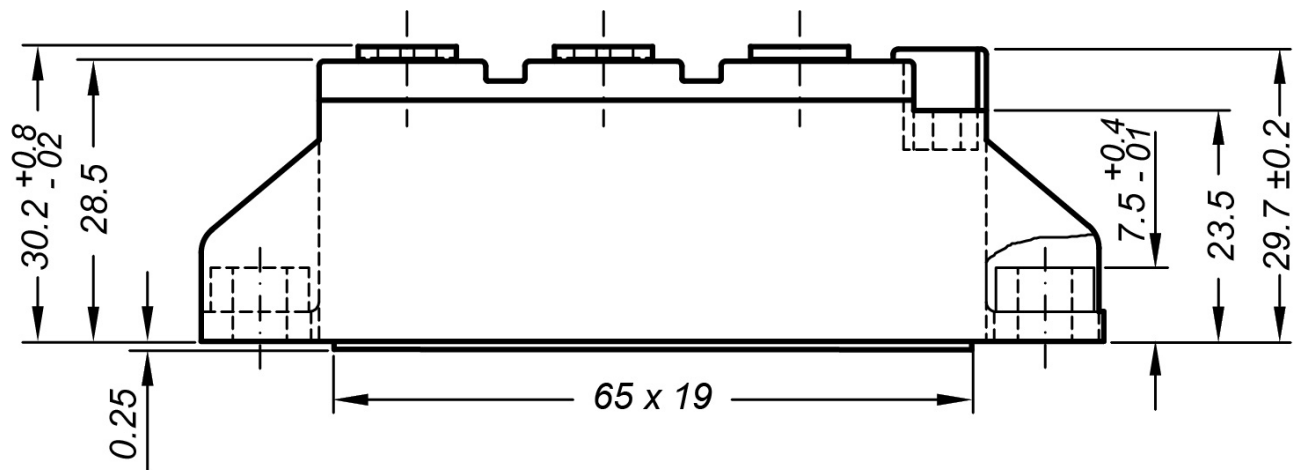
V

$R_{0\max}$  slope resistance \* 1.6

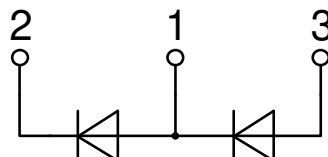
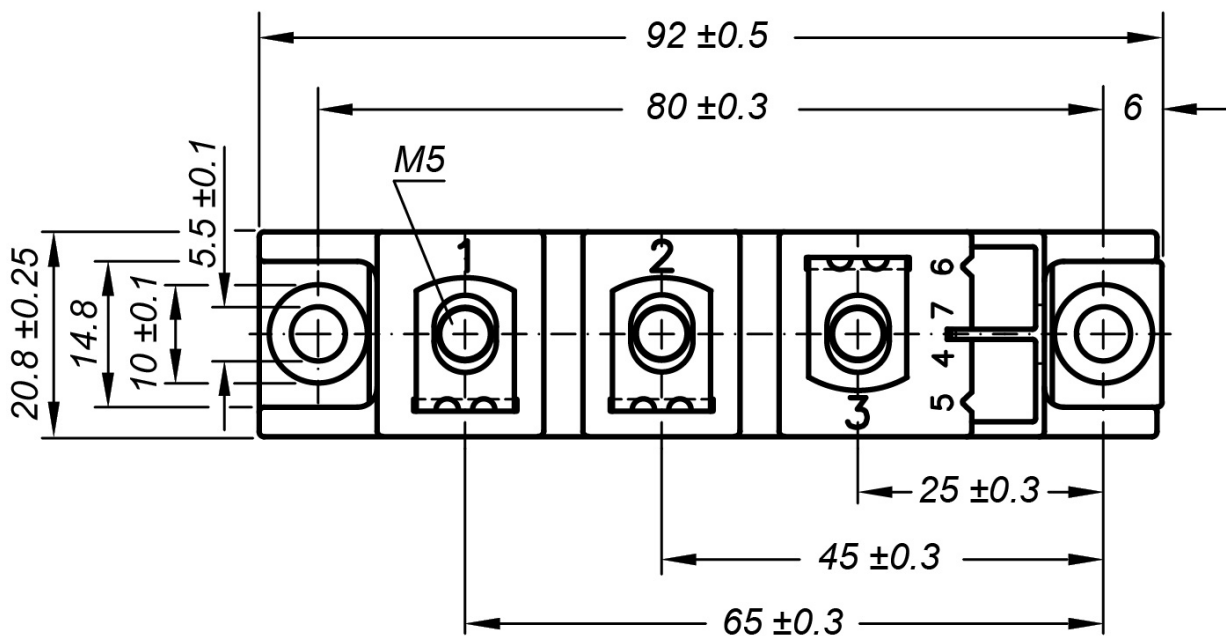
mΩ



**Outlines TO-240AA**



General tolerance: DIN ISO 2768 class „c“



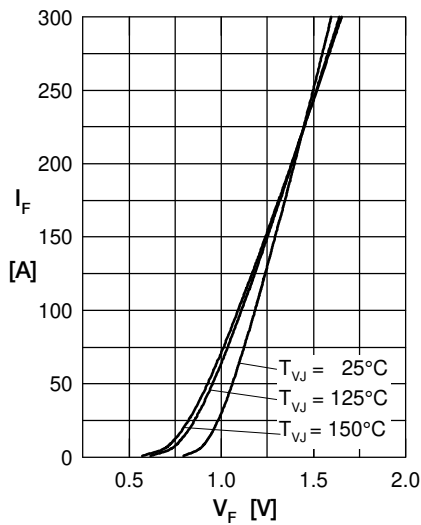
**Rectifier**


Fig. 1 Forward current versus voltage drop per diode

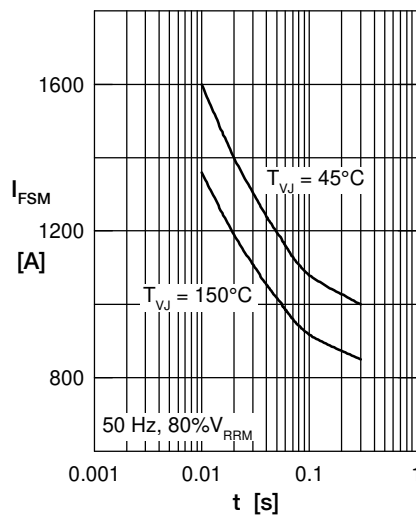


Fig. 2 Surge overload current vs. time per diode

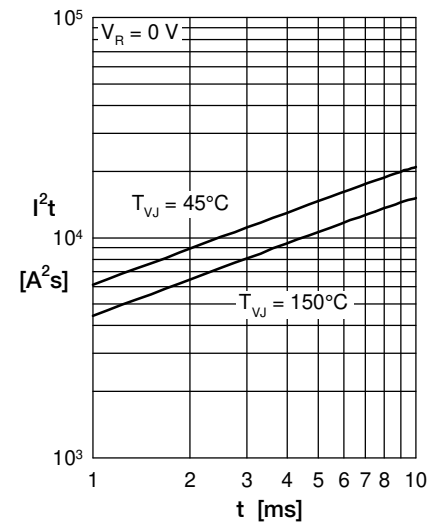


Fig. 3  $I^2t$  versus time per diode

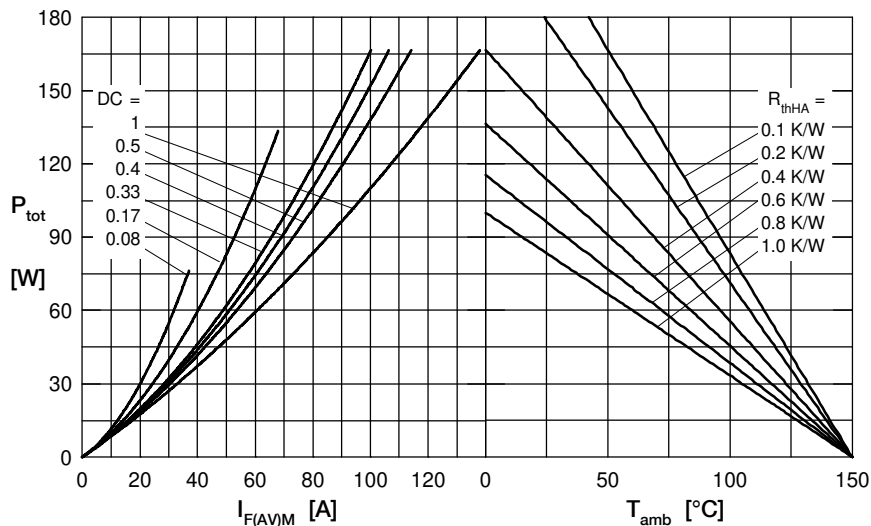


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

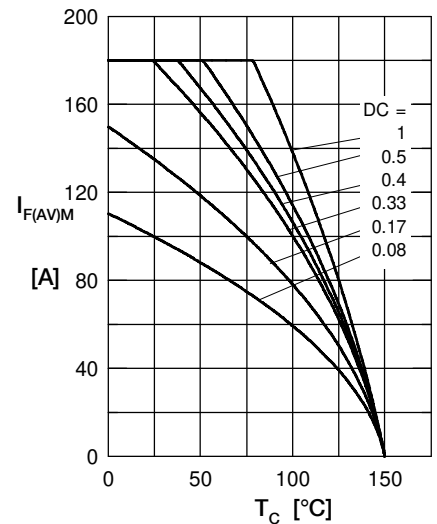


Fig. 5 Max. forward current vs. case temperature per diode

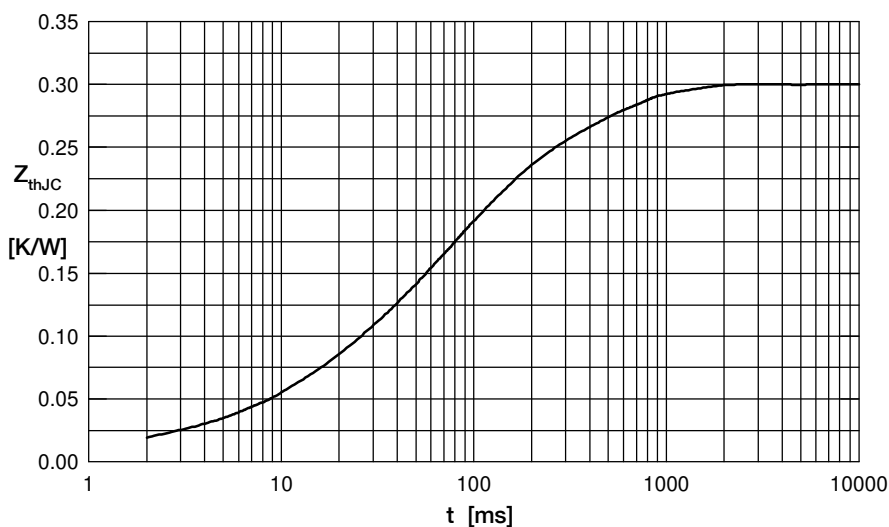


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.01            | 0.001     |
| 2 | 0.04            | 0.013     |
| 3 | 0.16            | 0.070     |
| 4 | 0.09            | 0.400     |